

1110-97825 PATENT

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Appl. No.	: 10/586,445	)	Confirmation No.: To be assigned
Applicant	: INAGAKI et al.	)	
Filed	: 27 January 2005	)	
Art Unit	: To be assigned	)	
Examiner	: To be assigned	)	
Docket No.	: 1110-97825	)	
Customer No.:	24628	)	
Title:	METHOD FOR PREDICTING	)	
	PRECIPITATION BEHAVIOR OF OXYGEN	)	
	IN SILICON SINGLE CRYSTAL, METHOD	)	
	FOR DETERMINING PRODUCTION	)	
	PARAMETER OF SILICON SINGLE	)	
	CRYSTAL, AND STORAGE MEDIUM FOR	)	
	STORING PROGRAM FOR PREDICTING	)	
	PRECIPITATION BEHAVIOR OF OXYGEN	)	
	IN SILICON SINGLE CRYSTAL	)	

Commissioner for Patents  
P.O. Box 1450  
Alexandria, Virginia 22313-1450

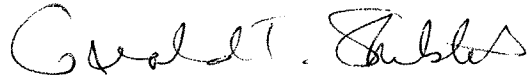
**CORRECTION**

Dear Sir:

We submit the following corrected TRANSMITTAL LETTER TO THE UNITED STATES DESIGNATED/ELECTED OFFICE (DO/EO/US) CONCERNING A SUBMISSION UNDER 35 U.S.C. 371 to correct unintentional defects in the transmittal letter. No new material has been added through the submission of these corrections.

Application No. 10/586,445

Respectfully submitted,

A handwritten signature in black ink, appearing to read "Gerald T. Shekleton". The signature is fluid and cursive, with the first name "Gerald" being more prominent than the last name "Shekleton".

Dated: 20 February 2009

**Gerald T Shekleton**

Reg. No. 27,466

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